

**T3050H-8E 30A TRIAC**

Rev.A.1.1

The T3050H-8E triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Compared to traditional triacs, T3050H-8E provides a very high switching capability up to junction temperatures of 150°C. Package TO-263 is RoHS compliant.

| Parameter | Symbol | Value | Unit |
|---|--------------|---------|------------------------|
| Storage junction temperature range | T_{stg} | -40-150 | |
| Operating junction temperature range | T_j | -40-150 | |
| Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$) | V_{DRM} | 800 | V |
| Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$) | V_{RRM} | 800 | V |
| RMS on-state current ($T_c=117^\circ\text{C}$) | $I_{T(RMS)}$ | 30 | A |
| Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$) | I_{TSM} | 270 | A |
| Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$) | | 297 | |
| I^2t value for fusing ($t_p=10\text{ms}$, $T_j=25^\circ\text{C}$) | I^2t | 365 | A^2s |
| Critical rate of rise of on-state current ($I_G=2 I_{GT}$, $f=100\text{Hz}$, $T_j=150^\circ\text{C}$) | di/dt | 100 | $\text{A}/\mu\text{s}$ |
| Peak gate current ($t_p=20\mu\text{s}$, $T_j=150^\circ\text{C}$) | I_{GM} | 4 | A 10031.186. 0 |

| | | | |
|--|----------|-----|----|
| Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.8) | V_{pp} | 1.2 | kV |
|--|----------|-----|----|

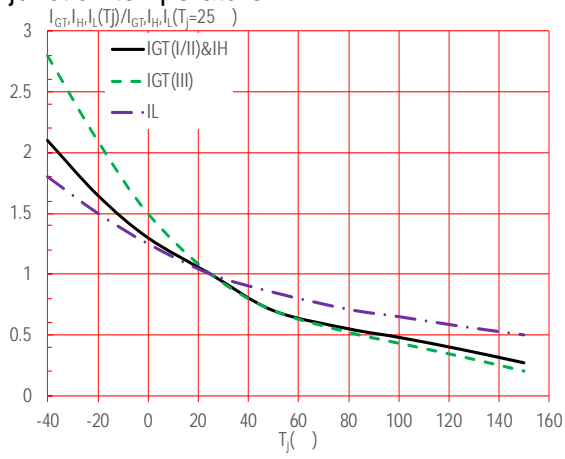
(T_j=25 unless otherwise specified)

| Symbol | Test Condition | Quadrant | Value | | Unit |
|----------------------|--|----------|-------|------|------------|
| I_{GT} | $V_D=12V R_L=33$ | - - | MAX. | 50 | mA |
| V_{GT} | | - - | MAX. | 1.3 | V |
| V_{GD} | $V_D=V_{DRM} T_j=150$ $R_L=3.3k$ | - - | MIN. | 0.15 | V |
| I_L | $I_G=1.2I_{GT}$ | - | MAX. | 80 | mA |
| | | | | 90 | |
| I_H | $I_T=500mA$ | | MAX. | 60 | mA |
| dV/dt | $V_D=540V$ Gate Open $T_j=150$ | | MIN. | 2000 | V/ μs |
| (dI/dt) _c | (dV/dt) _c =20V/ μs , $T_j=150$ | | MIN. | 30 | A/ms |
| t_{on} | $I_G=80mA I_A=400mA I_R=40mA$ $T_j=25$ | | TYP. | 15 | μs |
| t_{off} | | | | 100 | |

| Symbol | Parameter | | Value(MAX.) | Unit |
|-----------|---------------------------|-----------|-------------|---------|
| V_{TM} | $I_{TM}=42A t_p=380\mu s$ | $T_j=25$ | 1.5 | V |
| V_{TO} | Threshold voltage | $T_j=150$ | 0.7 | V |
| R_D | Dynamic resistance | $T_j=150$ | 16 | m |
| I_{DRM} | $V_D=V_{DRM} V_R=V_{RRM}$ | $T_j=25$ | 8 | μA |
| I_{RRM} | | $T_j=150$ | 8 | mA |

| Symbol | Parameter | Value | Unit |
|---------------|---|-------|------------|
| $R_{th(j-c)}$ | junction to case (AC) | 0.8 | W |
| $R_{th(j-a)}$ | junction to ambient (AC, in free air, $S=2cm^2$) | 45 | W |

FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature



| Order code | Voltage V_{DRM}/V_{RRM} (V) | IGT(mA) | Package | Base qty. (pcs) | Delivery mode |
|---------------------------|----------------------------------|---------|---------|--------------------|---------------|
| | | - - | | | |
| T3050H-8E T3050H-8E-TR | 800 | 50 | TO-263 | 50 | Tube |



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